

## Features

- ◆ Ultra low capacitance: 0.3pF typical (I/O to I/O)
- ◆ Ultra low leakage: nA level
- ◆ Low operating voltage: 5V
- ◆ Low clamping voltage
- ◆ Up to 4 data lines and one power line protects
- ◆ Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    - Air discharge: ±30kV
    - Contact discharge: ±25kV
  - IEC61000-4-4 (EFT) 40A (5/50ns)
  - IEC61000-4-5 (Lightning) :4 A(8/20μs)
- ◆ ROHS Compliant

## Ordering Information

Part Number	Qty per Reel	Reel Size
TPAZC199-04S	3000	7"

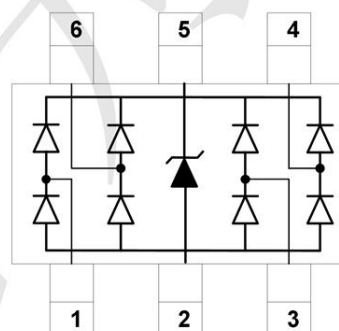
## Mechanical Characteristics

- ◆ Package: SOT23-6
- ◆ Lead Finish: Matte Tin
- ◆ Case Material: "Green" Molding Compound.
- ◆ UL Flammability Classification Rating 94V-0
- ◆ Moisture Sensitivity: Level 3 per J-STD-020

## Applications

- ◆ USB 2.0 and USB 3.0 Ports
- ◆ USB OTG
- ◆ Digital video interface(DVI)
- ◆ Monitor and Flat Panel Displays
- ◆ PCI Express and Serial SATA Ports
- ◆ Gigabit Ethernet
- ◆ IEEE 1394 firewire ports
- ◆ Consumer products (STB, DVD, DSC, DVC...)

## Dimensions and Pin Configuration



Circuit and Pin Schematic

**Absolute Maximum Ratings** (Tamb=25°C unless otherwise specified)

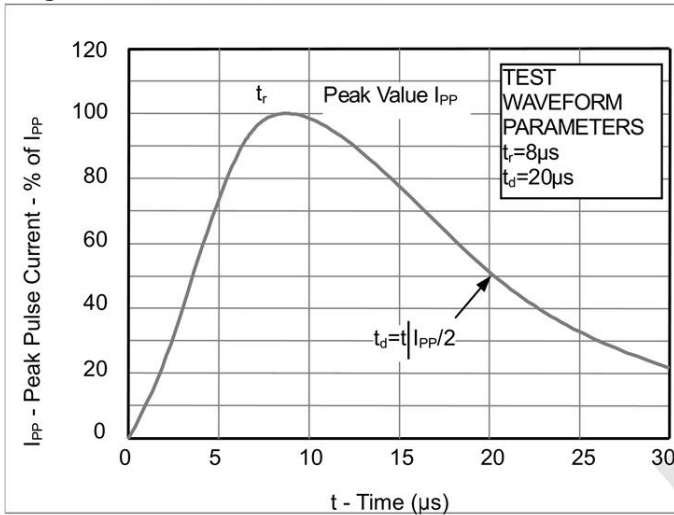
Parameter	Symbol	Value	Unit
Peak Pulse Power (tp=8/20μs)	PPP	100	W
Peak Pulse Current (tp=8/20μs)	I <sub>PP</sub>	4	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V <sub>ESD</sub>	±30 ±25	kV
Operating Temperature Range	T <sub>J</sub>	-55 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

**Electrical Characteristics** (TA=25°C unless otherwise specified)

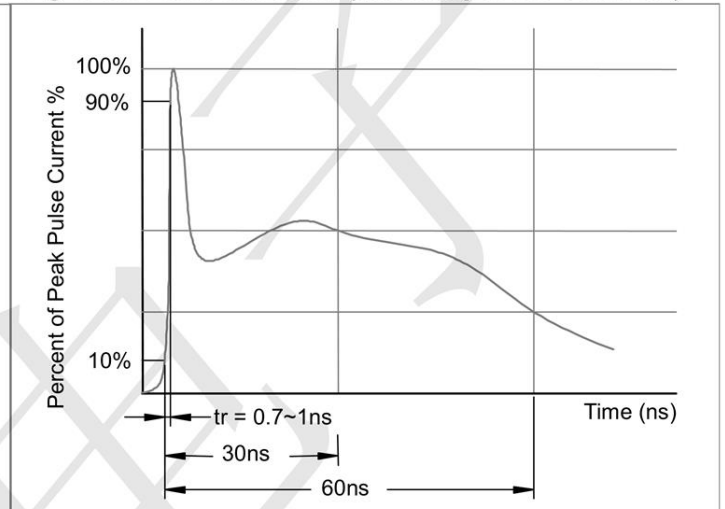
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V <sub>RWM</sub>			5	V	Any I/O pin to ground
Breakdown Voltage	V <sub>BR</sub>	6			V	I <sub>T</sub> = 1mA, any I/O pin to ground
Reverse Leakage Current	I <sub>R</sub>			0.5	μA	V <sub>RWM</sub> = 5V, any I/O pin to ground
Clamping Voltage	V <sub>C</sub>			15	V	I <sub>PP</sub> = 1A (8 x 20μs pulse) any I/O pin to ground
Clamping Voltage	V <sub>C</sub>			20	V	I <sub>PP</sub> = 4A (8 x 20μs pulse) any I/O pin to ground
Junction Capacitance	C <sub>J</sub>		0.3	0.4	pF	V <sub>R</sub> = 0V, f = 1MHz, between I/O pins
Junction Capacitance	C <sub>J</sub>			0.8	pF	V <sub>R</sub> = 0V, f = 1MHz, any I/O pin to ground

Note 1: I/O pins are Pin 1, 3, 4 and 6

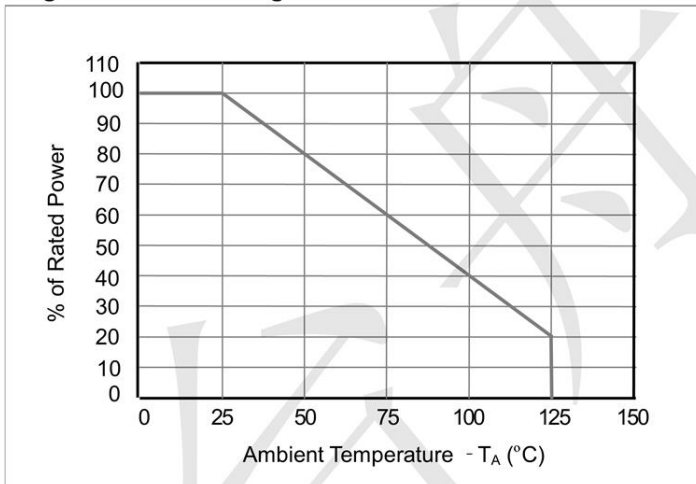
**Fig1. 8/20 $\mu$ s Pulse Waveform**



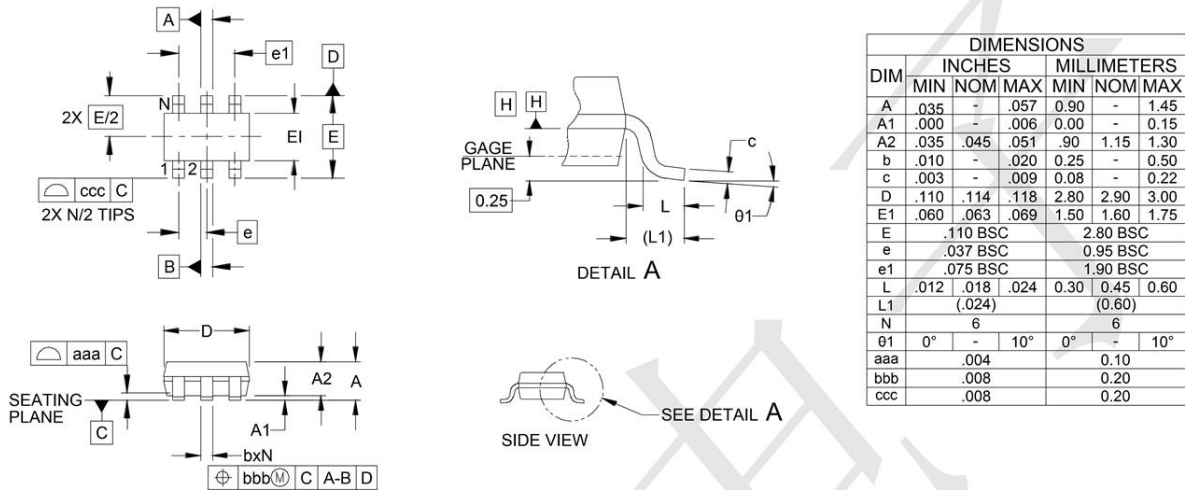
**Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)**



**Fig3. Power Derating Curve**



**Outline Drawing - SOT23-6**



**Land Pattern - SOT23-6**

